

## IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

IN RE APPLICATION OF: Jeffrey B. CASADY, et al.

ART UNIT: 2811

SERIAL NO.: 10/033,785

EXAMINER: Junghwa M. Im

FILING DATE: January 3, 2002

FOR:

SILICON CARBIDE AND RELATED WIDE-BANDGAP TRANSISTORS

ON SEMI-INSULATING EPITAXY FOR HIGH-SPEED, HIGH-POWER

**APPLICATIONS** 

## **AMENDMENT**

ASSISTANT COMMISSIONER FOR PATENTS PO BOX 1450 ALEXANDRIA, VA 22313-1450

SIR:

Responsive to the outstanding Office Action dated June 1, 2004, entry of the following amendments is respectfully requested.